# imall

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## MOS FET FK3306010L

## FK3306010L Silicon N-channel MOSFET

For switching

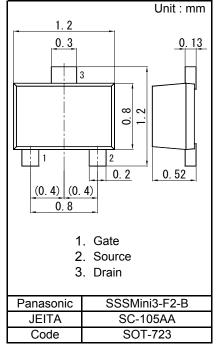
FK350601 in SSSMini3 type package

#### Features

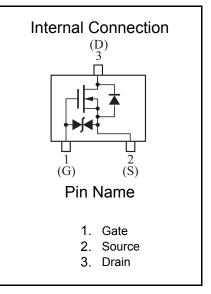
- Low drive voltage : 2.5 V drive
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

- Marking Symbol : CV
- Packaging

Embossed type (Thermo-compression sealing) : 10 000 pcs / reel (standard)



■ Absolute Maximum Ratings Ta = 25 °C							
Parameter	Symbol	Rating	Unit				
Drain-source voltage	VDS	60	V				
Gate-source voltage	VGS	±12	V				
Drain current	ID	100	mA				
Pulse drain current	IDp	200	mA				
Total power dissipation	PD	100	mW				
Channel temperature	Tch	150	°C				
Operating Ambient Temperature	Tstg	-40 to +85	°C				
Storage temperature	Tstg	-55 to +150	°C				

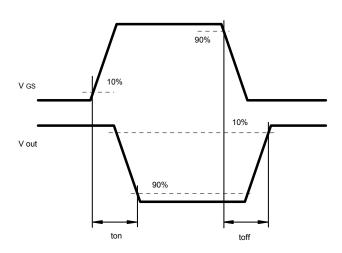


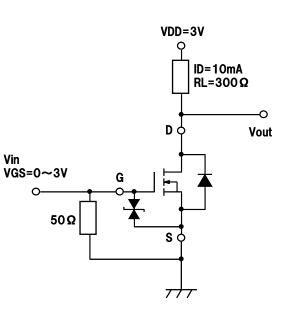
## **Panasonic**

## MOS FET FK3306010L

■ Electrical Characteristics Ta = 25 °C ± 3 °C								
Parameter	Symbol	Conditions M		Тур	Max	Unit		
Drain-source breakdown voltage	VDSS	ID = 1 mA, VGS = 0	60			V		
Drain-source cutoff current	IDSS	VDS = 60 V, VGS = 0			1.0	μA		
Gate-source cutoff current	IGSS	VGS = ±10 V, VDS = 0			±10	μA		
Gate threshold voltage	VTH	ID = 1.0 μA, VDS = 3.0 V	0.9	1.2	1.5	V		
Drain-source ON resistance	RDS(on)1	ID = 10 mA, VGS = 2.5 V		8	15	Ω		
	RDS(on)2	ID = 10 mA, VGS = 4.0 V		6	12	Ω		
Forward transfer admittance	Yfs	ID = 10 mA, VDS = 3 V, f = 1 kHz	20	60		mS		
Input capacitance	Ciss			12		pF		
Output capacitance	Coss	VDS = 3 V, VGS = 0, f = 1 MHz		7		pF		
Reverse transfer capacitance	Crss			3		pF		
Turn-on time <sup>*1</sup>	ton	VDD = 3 V, VGS = 0 to 3 V, RL = 300 Ω		100		ns		
Turn-off time <sup>*1</sup>	toff	VDD = 3 V, VGS = 3 to 0 V, RL = 300 Ω		100		ns		

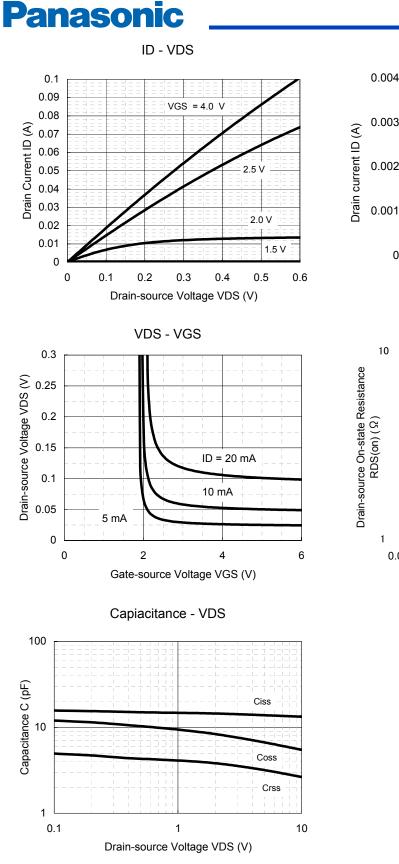
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors. 2. \*1 Turn-on and Turn-off test circuit





Established : 2010-05-20 Revised : 2013-08-08

## MOS FET FK3306010L



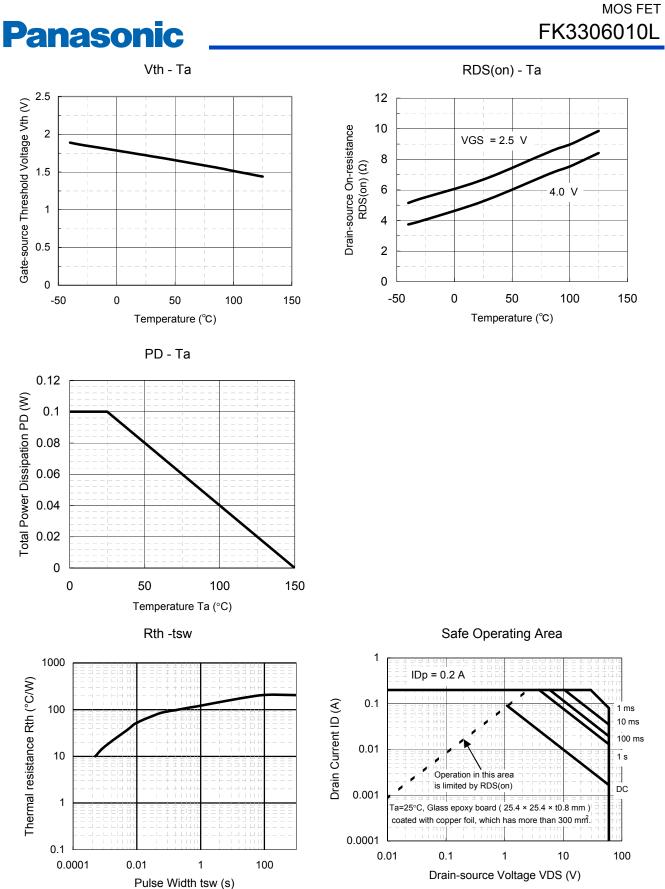
0.003 25 0.002 °C -40 °C 0.001 0 3 0 1 2 Gate-source voltage VGS (V) RDS(on) - ID 10 2.5 V Drain-source On-state Resistance RDS(on) (  $\Omega$  ) VGS = 4.0 V 1 0.001 0.1 0.01 Drain Current ID (A)

ID - VGS

Ta = 85 °C

Established : 2010-05-20 Revised : 2013-08-08

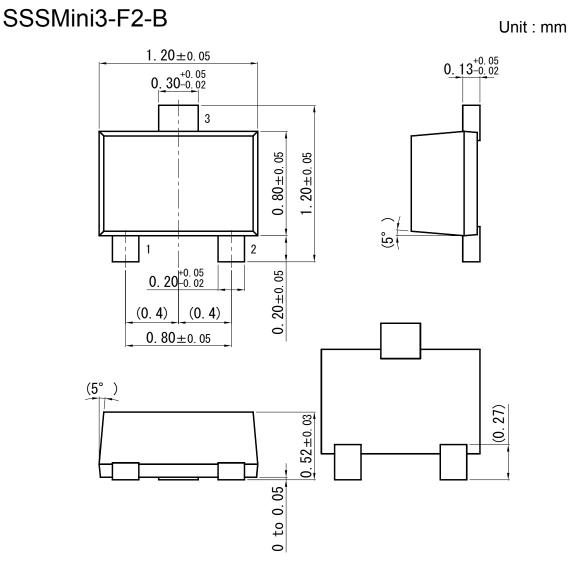




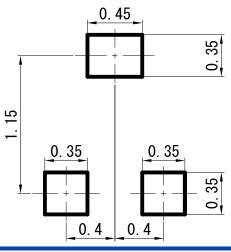
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MOS FET FK3306010L



■ Land Pattern (Reference) (Unit : mm)



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Established : 2010-05-20 Revised : 2013-08-08

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